Ordering number : ENA2032A

LA4535MC

Monolithic Linear IC

Power Amplifier for 1.5V Headphone Stereo

ON Semiconductor®

http://onsemi.com

Features

- Low current drain.
- 16Ω load drive capability.
- Excellent reduced voltage characteristics.
- Excellent power supply ripple rejection.
- Minimum number of external parts required (no input capacitor, feedback capacitor required).
- Less harmonic interference in radio band.
- On-chip power switch function, muting function.

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V_{CC} max	Quiescent	4.5	V
Allowable power dissipation	Pd max		290	mW
Operating temperature	Topr		–20 to +75	°C
Storage temperature	Tstg		–40 to +125	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Operating Conditions at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Recommended supply voltage	V_{CC}		1.5	V
Operating voltage range	V_{CC} op		0.9 to 4.0	V
Recommended load resistance	R_L		16 to 32	Ω

Electrical Characteristics at Ta = 25°C, R_L = 16Ω, Rg = 600Ω, See specified Test Circuit.

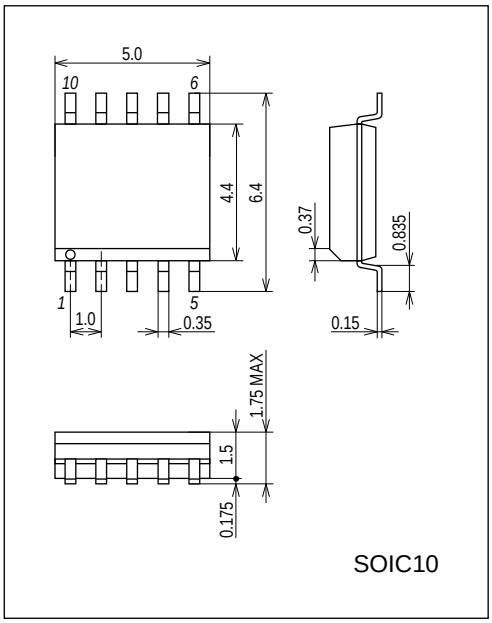
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Quiescent current *1	$I_{CCO}1$	V_{CC} = 1.2V, quiescent		3.5	6.0	mA
	$I_{CCO}2$	V_{CC} = 2.5V, pin 10 →GND		1.5	2.5	mA
	$I_{CCO}3$	V_{CC} = 2.5V, pin 1 →GND			1.0	μA
Voltage gain	VG1	V_{CC} = 1.2V, f = 1kHz, V_O = –20dBm	20.5	22	23	dB
	VG2	V_{CC} = 0.9V, f = 1kHz, V_O = –20dBm	19.5	22	23	dB
Voltage gain difference	ΔVG1	V_{CC} = 1.2V, f = 1kHz, V_O = –20dBm			1.0	dB
	ΔVG2	V_{CC} = 0.9V, f = 1kHz, V_O = –20dBm			1.0	dB
Total harmonic distortion	THD	V_{CC} = 1.2V, f = 1kHz, P_O = 0.5mW		0.8	1.5	%
Output power	P_O	V_{CC} = 1.5V, f = 1kHz, THD = 10%	5	8		mW
Crosstalk	CT	V_{CC} = 1.2V, f = 100Hz, Rg = 1kΩ, V_O = –20dB	40	45		dB
Ripple rejection	SVRR	V_{CC} = 1.0V, f = 100Hz, Rg = 1kΩ, V_R = –30dBm, BPF = 100Hz	45	50		dB
Output noise voltage	V_{NO}	V_{CC} = 2.5V, Rg = 1kΩ, BPF= 20Hz to 20kHz		30	44	μV
Power off effect	V_O(off)	V_{CC} = 0.9V, f = 100Hz, pin 1 →GND, V_{IN} = –10dB			-80	dBm
Muting effect	V_O(MT)	V_{CC} = 0.9V, f = 100Hz, pin 10 → GND, V_{IN} = –10dB			-80	dBm
Power on current sensitivity	I_1(on)	V_{CC} = 0.85V, V5 ≥ 0.5V		0.1	1.0	μA
Power off voltage sensitivity	V_1(off)	V_{CC} = 0.85V, V5 ≤ 0.1V	0.5	0.65		V
Muting off current sensitivity	I_{10}(off)	V_{CC} = 0.85V, V5 ≥ 0.5V		0.3	1.0	μA
Muting on voltage sensitivity	V_{10}(on)	V_{CC} = 0.85V, V5 ≤ 0.1V	0.5	0.65		V

Note) The quiescent current is represented by the current flowing into pin 6. The respective maximum currents flowing into pin 1 and pin 10 are calculated by (V pin –0.5) / 16 [V/ kΩ] and the total current increases by these current values.

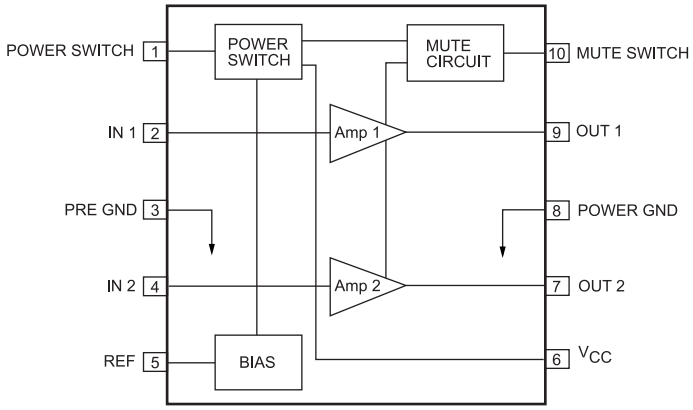
Package Dimensions

unit : mm (typ)

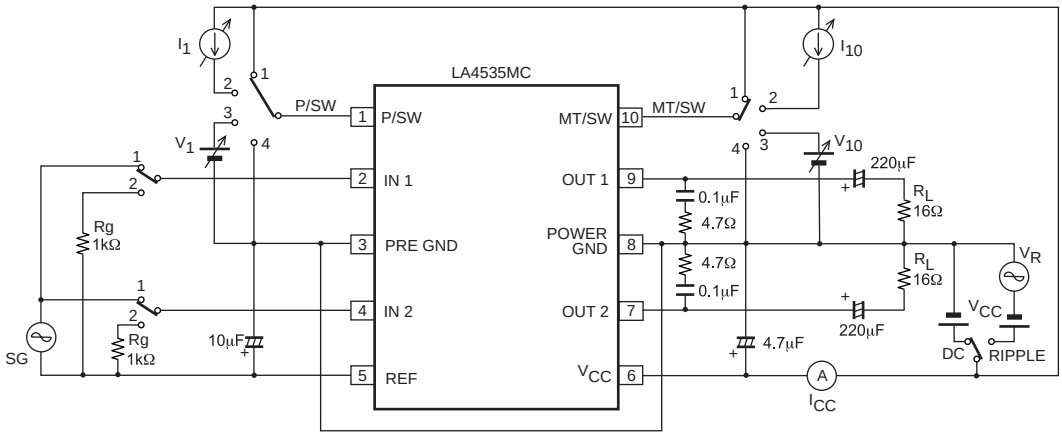
3426



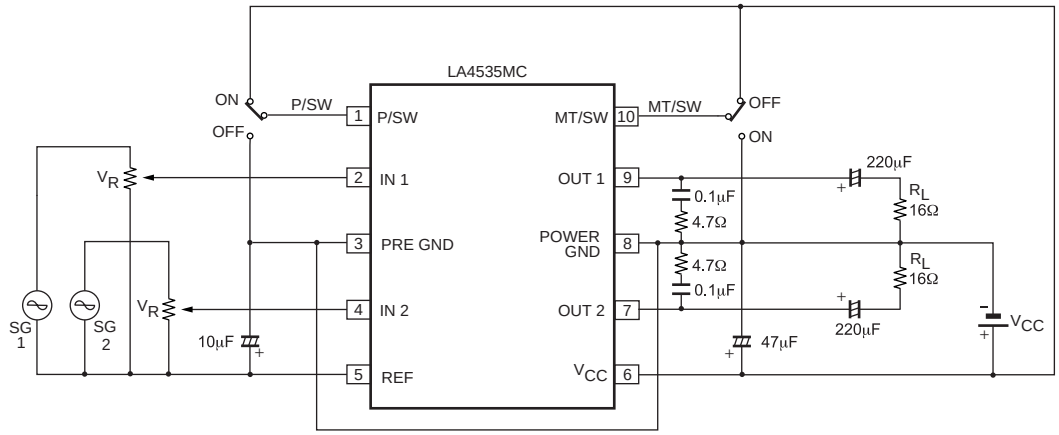
Block Diagram



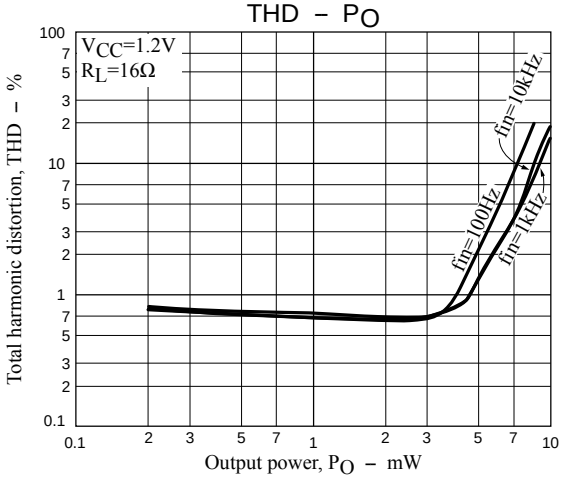
Test Circuit



Sample Application Circuit



THD – P_O



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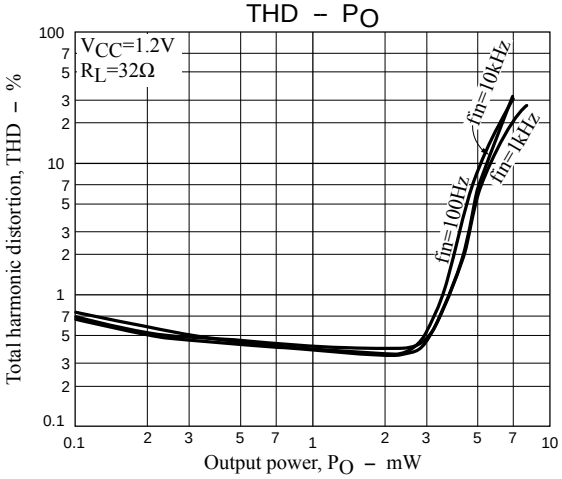
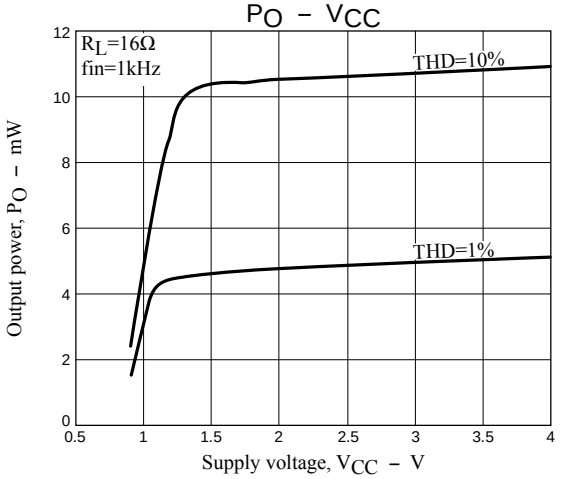
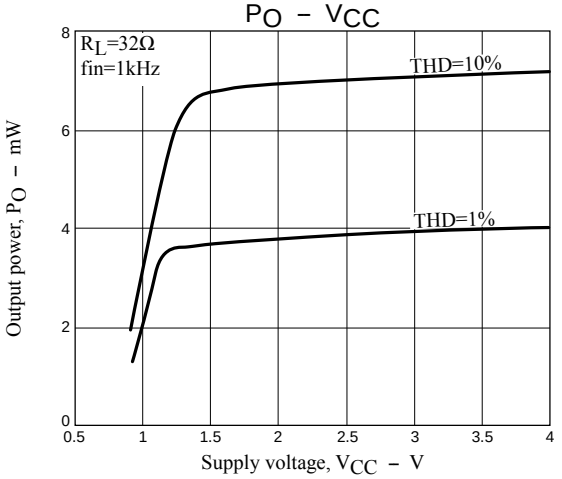


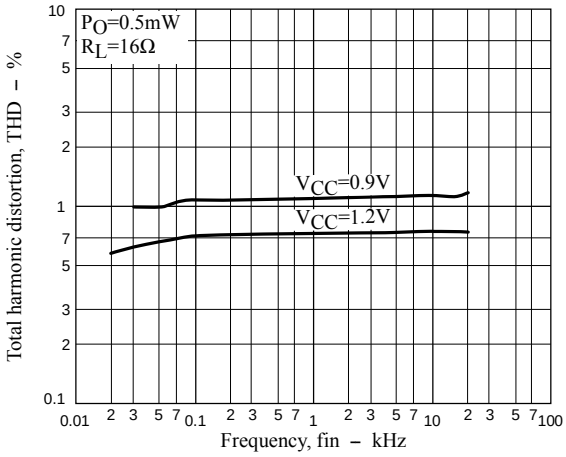
P_O – V_{CC}



P_O – V_{CC}



THD – fin



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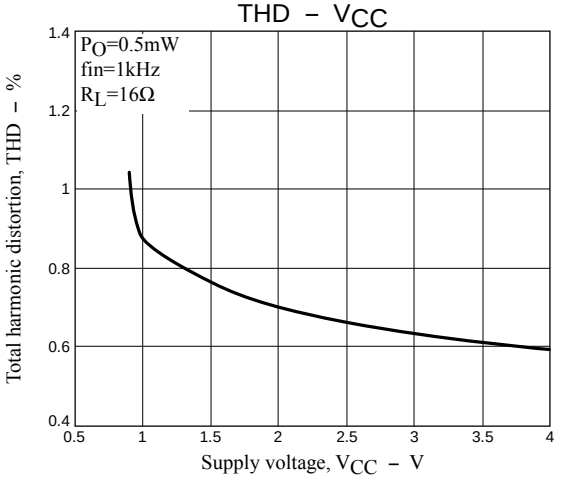
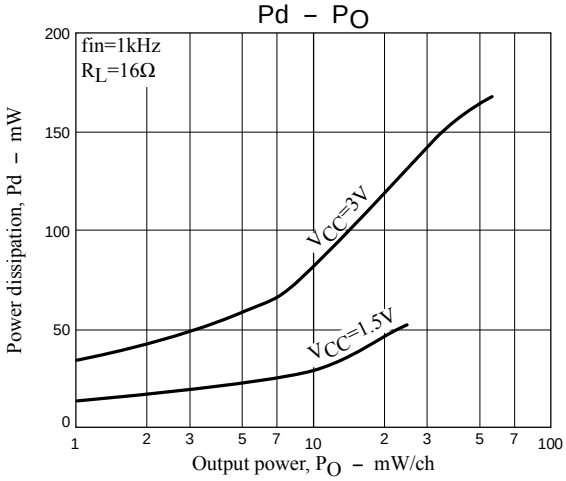
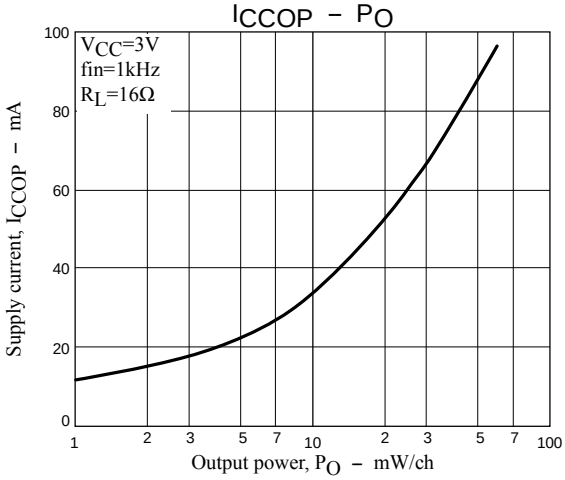


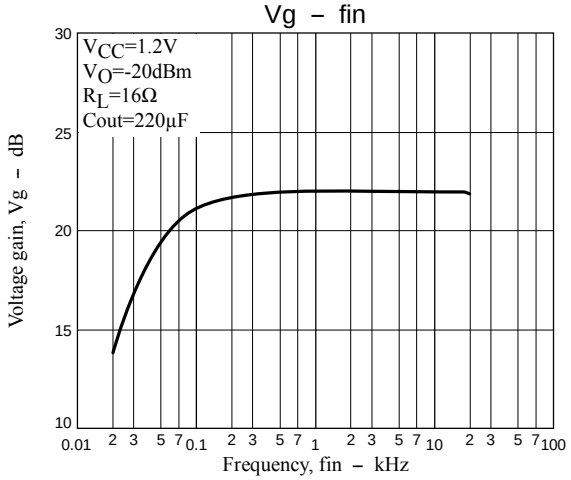
Pd – P_O



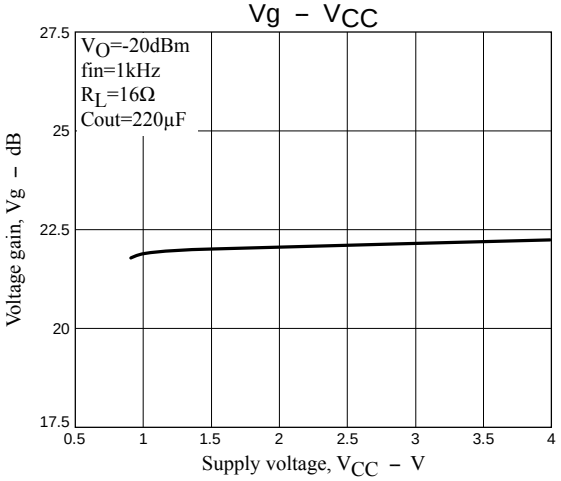
I_{CCOP} – P_O



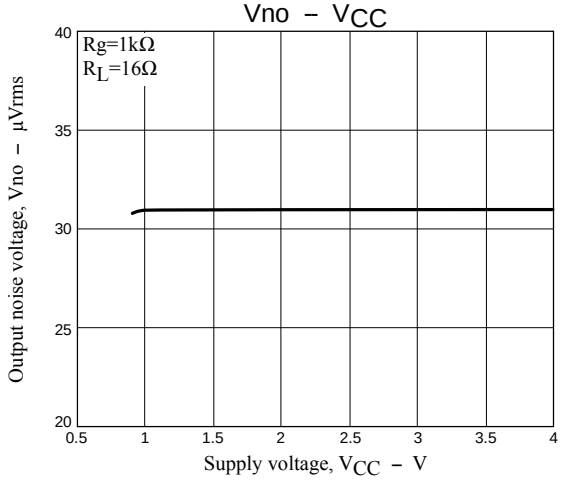
Vg – fin



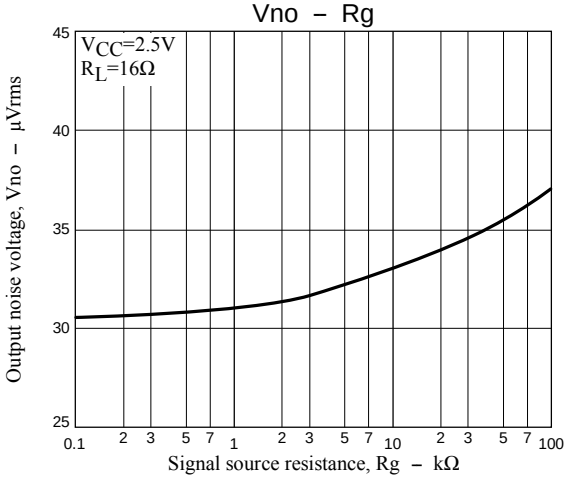
Vg – VCC



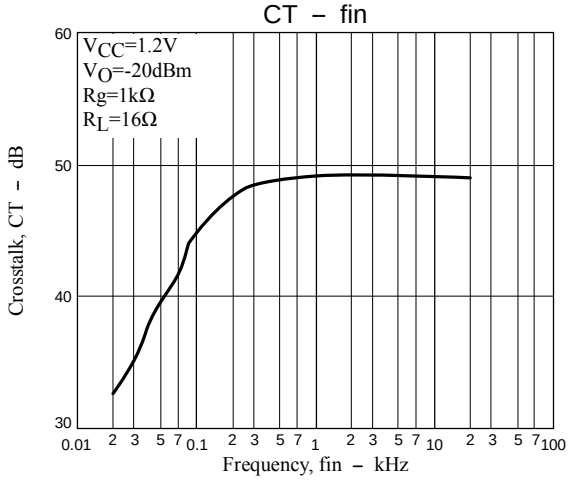
Vno – VCC



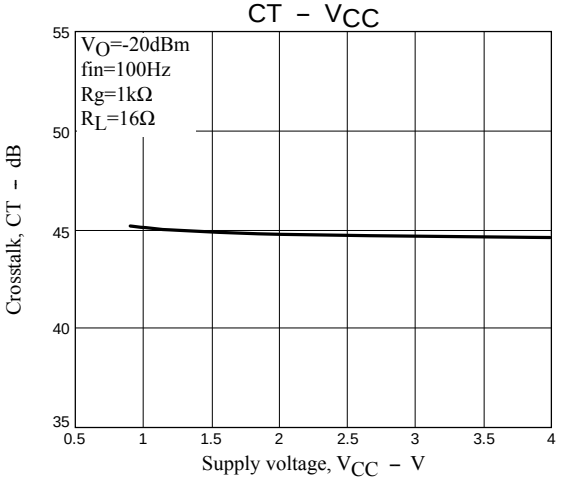
Vno – Rg



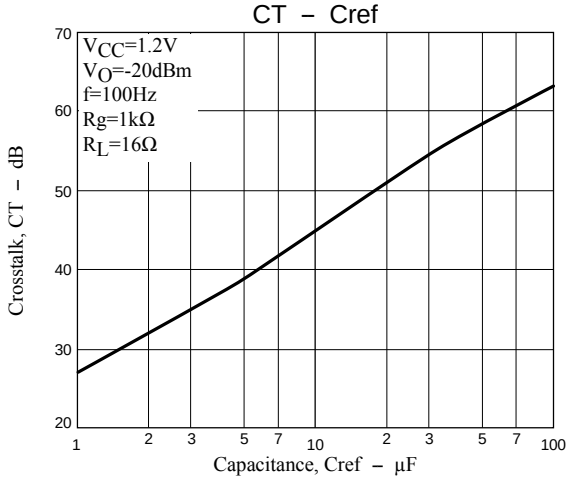
CT – fin



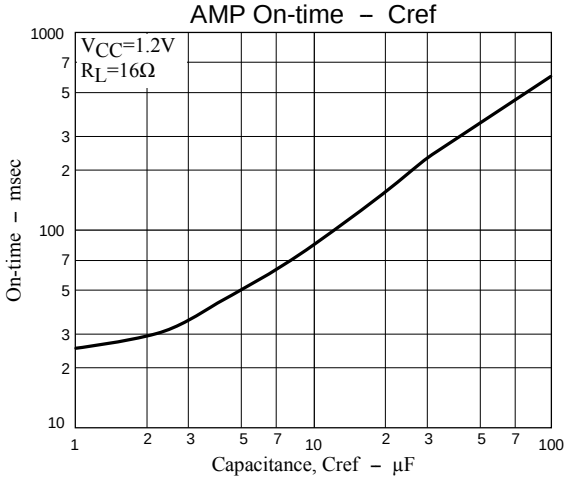
CT – VCC



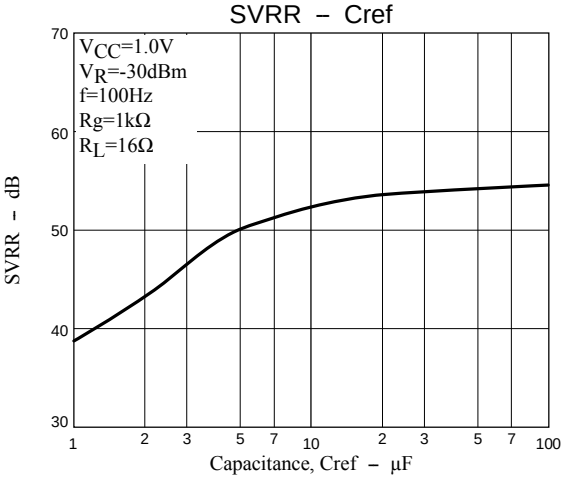
CT – Cref



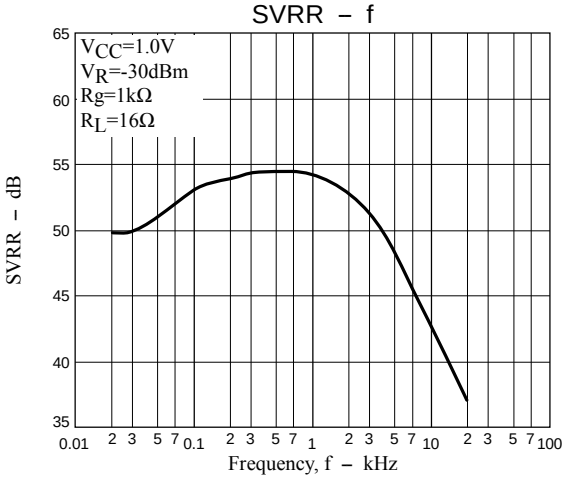
AMP On-time – Cref



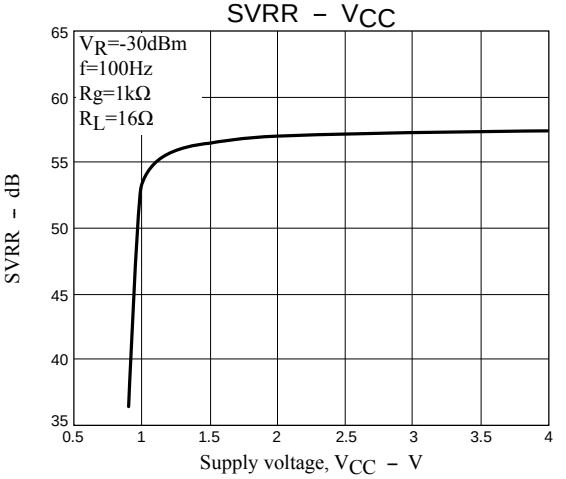
SVRR – Cref



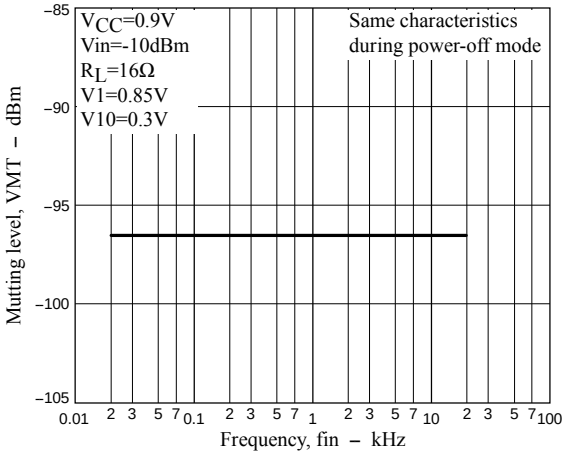
SVRR – f



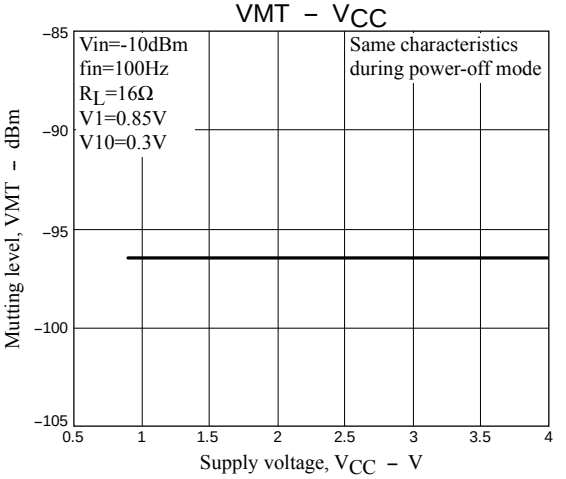
SVRR – V_{CC}



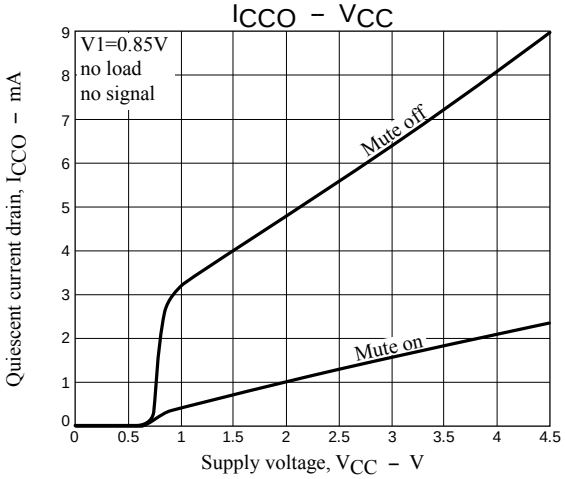
VMT – fin



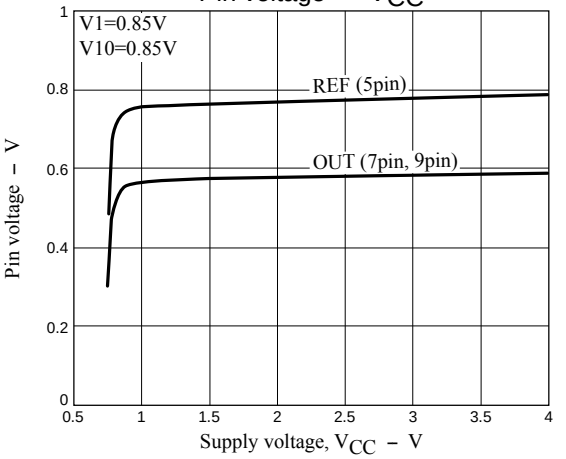
VMT – V_{CC}



I_{CCO} – V_{CC}



Pin voltage – V_{CC}



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- Консультации по применению компонента;
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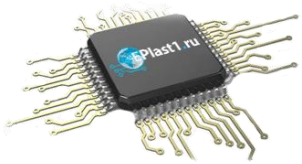
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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